**Preferred Device** 

# SWITCHMODE™ Power Rectifier

These state-of-the-art devices are designed for use in switching power supplies, inverters and as free wheeling diodes.

#### **Features**

- Ultrafast 25 Nanosecond Recovery Times
- 175°C Operating Junction Temperature
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction
- These are Pb-Free Devices\*

#### **Mechanical Characteristics:**

- Case: Epoxy, Molded
- Weight: 0.4 Gram (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Cathode Indicated by Polarity Band

## **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	200 -	V
Average Rectified Forward Current (Note 1) (Square Wave Mounting Method #3 Per Note 3)	I <sub>F(AV)</sub>	2.0 @ T <sub>A</sub> = 90°C	Α
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	35	Α
Operating Junction Temperature and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 65 to +175	°C

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	(Note 3)	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

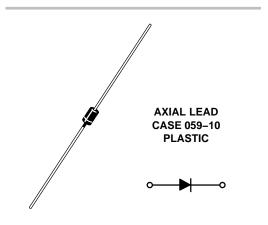
1. Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.



## ON Semiconductor®

http://onsemi.com

## ULTRAFAST RECTIFIER 2.0 AMPERES – 200 VOLTS



#### **MARKING DIAGRAM**



A = Assembly Location

MUR220 = Device Code

YY = Year WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MUR220	Axial Lead**	1000 Units / Bulk
MUR220G	MUR220G Axial Lead** 1000 Units / E	
MUR220RL	Axial Lead**	5000 / Tape & Reel
MUR220RLG	Axial Lead**	5000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**Preferred** devices are recommended choices for future use and best overall value.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

<sup>\*\*</sup>This package is inherently Pb-Free.

## **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 2) $ \begin{aligned} (I_F = 2.0 \text{ Amp, } T_J = 150^{\circ}\text{C}) \\ (I_F = 2.0 \text{ Amp, } T_J = 25^{\circ}\text{C}) \end{aligned} $	VF	0.75 0.95	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_J = 150^{\circ}\text{C}$ ) (Rated dc Voltage, $T_J = 25^{\circ}\text{C}$ )	i <sub>R</sub>	50 2.0	μΑ
Maximum Reverse Recovery Time $ \begin{aligned} (I_F = 1.0 \text{ Amp, di/dt} = 50 \text{ Amp/}\mu\text{s}) \\ (I_F = 0.5 \text{ Amp, } I_R = 1.0 \text{ Amp, } I_{REC} = 0.25 \text{ A}) \end{aligned} $	t <sub>rr</sub>	35 25	ns
Maximum Forward Recovery Time (I <sub>F</sub> = 1.0 A, di/dt = 100 A/μs, I <sub>REC</sub> to 1.0 V)	t <sub>fr</sub>	25	ns

<sup>2.</sup> Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

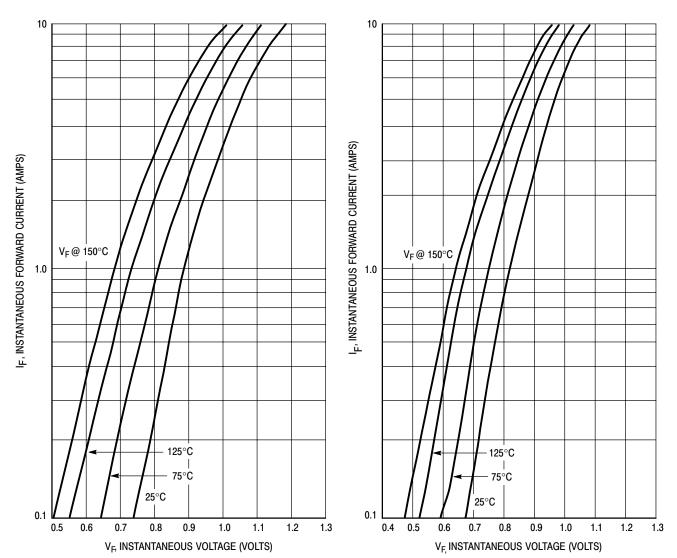


Figure 1. Maximum Forward Voltage

Figure 2. Typical Forward Voltage

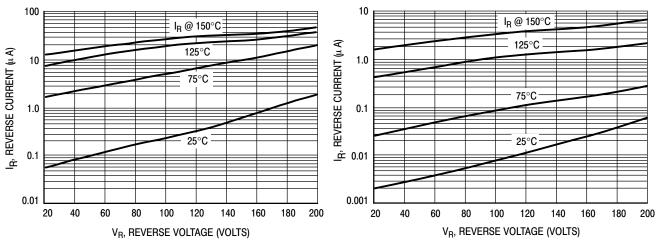
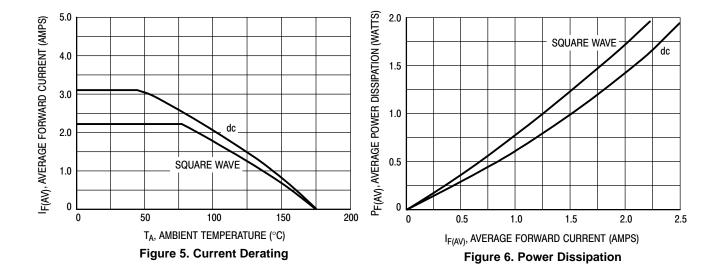


Figure 3. Maximum Reverse Current

Figure 4. Typical Reverse Current



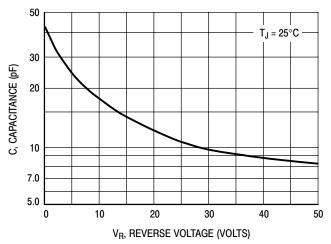


Figure 7. Typical Capacitance

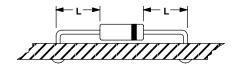
## **NOTE 3. – AMBIENT MOUNTING DATA**

Data shown for Thermal Resistance, Junction-to-Ambient ( $R_{\theta JA}$ ) for the mountings shown is to be used as typical guideline values for preliminary engineering or in case the tie point temperature cannot be measured.

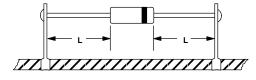
TYPICAL VALUES FOR  $R_{\theta \text{JA}}$  IN STILL AIR

Mounting		Lead Length, L			
Method		1/8	1/4	1/2	Units
1		52	65	72	°C/W
2	$R_{\theta JA}$	67	80	87	°C/W
3			50		°C/W

## **MOUNTING METHOD 1**

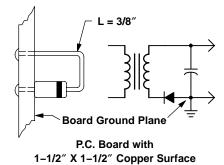


## **MOUNTING METHOD 2**



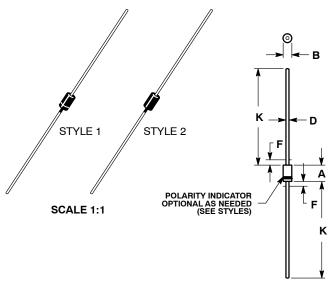
**Vector Pin Mounting** 

## **MOUNTING METHOD 3**



## **AXIAL LEAD** CASE 59-10 ISSUE U

**DATE 15 FEB 2005** 



STYLE 2:

NO POLARITY

STYLE 1: PIN 1. CATHODE (POLARITY BAND)

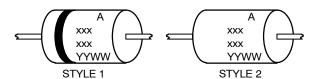
2. ANODE

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

- CONTROLLING DIMENSION: INCH.
  ALL RULES AND NOTES ASSOCIATED WITH
  JEDEC DO-41 OUTLINE SHALL APPLY
  POLARITY DENOTED BY CATHODE BAND.
  LEAD DIAMETER NOT CONTROLLED WITHIN F
  DIMENSION.

ĺ		INCHES		MILLIM	ETERS
l	DIM	MIN MAX		MIN	MAX
[	Α	0.161	0.205	4.10	5.20
I	В	0.079	0.106	2.00	2.70
I	D	0.028	0.034	0.71	0.86
I	F		0.050		1.27
I	K	<b>K</b> 1.000		25.40	

## **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code = Assembly Location Α

YY = Year WW = Work Week

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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DESCRIPTION:	AXIAL LEAD		PAGE 1 OF 1

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